

# High Q – High G Studies on single cell Medium Grain Nb cavities

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- Introduction refresher on MG Nb material.
- Performance of 1.3 GHz 1-Cell HRRR MG Nb SRF Cavity for High Q High G surface treatments.
- Flux Expulsion improvement of MG Nb cavity with high temperature annealing





- Medium Grain (MG) Nb is cost effective compared to FG Nb due to its manufacturing process.
- At KEK, two 1-cell MG Nb cavities were manufactured and are being tested for various High Q - High G surface treatments.
- MG Nb 1-Cell cavities have significant orange peel effect on its surface.
- In this presentation, the performance of MG Nb 1-Cell cavities are summarized and compared with FG Nb 1-Cell cavity.

# Niobium for 9-Cell 1.3 GHz SRF Cavity







# <u>Performance of 1-Cell MG Nb Cavities</u> for High Q – High G Surface Treatments



## VT Parameters for HRRR MG Nb Cavity









#### R18 & R18b HRRR MG Nb Tesla cavity manufactured at KEK-CFF



#### High Q – High G VT Results for MG Nb 1-Cell Cavity



- No degradation in Eacc after quenching, degradation in Q<sub>0</sub> expected due to trapped flux.
- R18 maximum Eacc is > 35 MV/m for all High G surface treatments.
- R18b Eacc > 35 MV/m achieved only for Standard treatment, but  $Q_0$  was higher for high Q treatments w.r.t R18.

### MG Nb 1-Cell Cavity High Q-High G comparison with FG Nb



Parameters @ 2.0 K	MG Nb R18 E <sub>acc</sub> max [MV/m]	MG Nb R18b E <sub>acc</sub> max [MV/m]	FG Nb E <sub>acc</sub> max [MV/m]	MG Nb R18 Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	MG Nb R18b Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	FG Nb Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	
Standard Treatment (120 °C 48h)	38.8	35.4	> 35	1.75E+10		~ 2E10	
2-step baking (70°C 4h + 120°C 48h)	35.0	33.5	> 35	1.77E+10	1.78E+10 (@ 33.5 MV/m)	~ 2E10	
Furnace baking <mark>(200 °C * 3hrs)</mark>	37.0	32.7	38.0	1.87E+10	1.97E+10 (@ 32.7 MV/m)	2.25E+10	
Furnace baking <mark>(250 °C * 3hrs)</mark>	29.6	27.5	31.0	-	-	-	
Furnace baking (800 °C) (300 °C * 3hrs)	24.0	22.0	-	-	-	-	

MG Nb R18 Q <sub>o</sub> max	MG Nb R18b Q <sub>o</sub> max	FG Nb Q <sub>o</sub> max			
-	-	-			
-	-	-			
-	-	-			
2.76E+10	3.27E+10	3.67E+10			
3.65E+10	4.04E+10	-			







MG Nb VT results with and without Trapped Flux Case Superconducting Applied Superconducting Accelerators



- Flux trapped measurement was taken by applying 20 mG of magnetic flux with Solenoid Coil during superconducting transition.
- No degradation in Eacc due to trapped flux.
- Degradation in Q<sub>0</sub> expected due trapped flux.
- Q<sub>0</sub> degradation is highest with 300 °C\*3h Furnace baking.
- Q<sub>0</sub> degradation due trapped flux in high G recipes like
  200 °C furnace and 2-step baking was the least.

# Flux Sensitivity for MG Nb





Flux sensitivity of 1-Cell MG Nb cavity is similar to 1-Cell FG Nb standard baked cavity.



# Performance Improvement of 1-Cell MG Nb Cavities with 900 °C annealing

#### 800 and 900 °C Annealing Performance Comparison





• Comparison of 300 °C furnace baking with same VT procedure

• Significant improvement in maximum  $Q_0$  from 3.6E10 -> 4.9E10 at Eacc = 16 MV/m, Eacc remained same.

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### **Resistance Deconvolution**





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### MG Nb 1-Cell Cavity High Q-High G comparison with FG Nb



Parameters @ 2.0 K	MG Nb R18 E <sub>acc</sub> max [MV/m]	MG Nb R18b E <sub>acc</sub> max [MV/m]	FG Nb E <sub>acc</sub> max [MV/m]	MG Nb R18 Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	MG Nb R18b Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	FG Nb Q <sub>0</sub> @ E <sub>acc</sub> = 35 MV/m	MG Nb R18 Q <sub>o</sub> max	MG Nb R18b Q <sub>o</sub> max	FG Nb Q <sub>o</sub> max
Standard Treatment <mark>(120 °C 48h)</mark>	38.8	35.4	> 35	1.75E+10		~ 2E10	-	-	-
2-step baking <mark>(70°C 4h + 120°C 48h)</mark>	35.0	33.5	> 35	1.77E+10	1.78E+10 (@ 33.5 MV/m)	~ 2E10	-	-	-
Furnace baking <mark>(200 °C * 3hrs)</mark>	37.0	32.7	38.0	1.87E+10	1.97E+10 (@ 32.7 MV/m)	2.25E+10	-	-	-
Furnace baking <mark>(250 °C * 3hrs)</mark>	29.6	27.5	31.0	-	-	-	2.76E+10	3.27E+10	3.67E+10
Furnace baking (800 °C) <mark>(300 °C * 3hrs)</mark>	<mark>24.0</mark>	22.0	-	-	-	-	<mark>3.65E+10</mark>	4.04E+10	-
Furnace baking (900 °C) <mark>(300 °C * 3hrs)</mark>	<mark>23.5</mark>	ТВС	25.0	-	-	-	<b>↓</b> 4.9E+10 •		5.1E+10





- MG Nb is a cost-effective material with isotropic mechanical properties and its 1-Cell cavity performance clears ILC specification.
- Even with orange peel effect, the performance of the 1-Cell MG Nb cavity is on par with FG Nb cavity.
- Moreover, the flux expulsion of MG Nb cavity is comparable to FG Nb material and improves drastically with 900 C\*3 hr annealing.
- For surface treatments highly sensitive to trapped flux, 900 C\*3 hr annealing improves the Q<sub>0</sub> of MG Nb cavity drastically.





# Thank You for Your Attention!





# Appendix



## Mechanical Property of MG Nb





#### 🛛 FG Nb 🛛 MG Nb 🔟 LG Nb

#### **Mechanical strength of MG-Nb** achieved the criteria of **HPGS** regulation for KEK/STF-Cavity

\* FG Nb and LG Nb data is for middle RRR annealed material (M. Yamanaka et al., SRF'21 WEPFDV005.

MG Nb data: A. Kumar et al., SRF2021 MOPCAV004

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# Manufacturing of LG & MG Nb





\* The "Nb forged ingot" technology originated by ATI, and SRF (GHz) cavities planned to be fabricated and RF tested by KEK and JLab, to qualify this approach, in collaboration of ATI, ODU/BSCE, JLab, and KEK.

## MG Nb R18b v/s R8 at 2.0 K







H. Ito, H. Araki, and K. Umemori, "Surface Resistance and Trapped Flux Sensitivity as Function of Baking Temperature", presented at the 21th Int. Conf. RF Supercond. (SRF'23), Grand Rapids, MI, USA, Jun. 2023, paper TUIXA03

## **Resistance Deconvolution**





Rres lowest and same for 2-step and Furnace baking

### <u>Comparison of R18 and R8 at 2.0 K for</u> 300C Furnace baking







H. Ito, H. Araki, and K. Umemori, "Surface Resistance and Trapped Flux Sensitivity as Function of Baking Temperature", presented at the 21th Int. Conf. RF Supercond. (SRF'23), Grand Rapids, MI, USA, Jun. 2023, paper TUIXA03